

Uni-directional 12V High Capacitance ESD Protector

Description

The PESDHC2FD12VU ESD protector is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PESDHC2FD12VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PESDHC2FD12VU is available in a DFN1006-2L package with working voltages of 12 volt. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium.



DFN1006-2L(Bottom View)

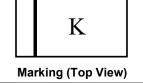
Feature

- > 180W Peak pulse power per line (t_P = 8/20µs)
- DFN1006-2L package
- Replacement for MLV(0402)
- Unidirectional configurations
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)

Applications

- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players

Pin 1 Circuit Diagram

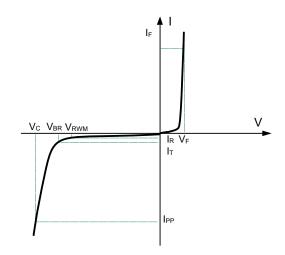


Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- ➤ Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- ➤ Pin flatness:≤3mil

Electronics Parameter

Symbol	Parameter
V _{RWM}	Peak Reverse Working Voltage
I _R	Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I⊤
Ι _Τ	Test Current
I _{PP}	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ I _{PP}
P _{PP}	Peak Pulse Power
CJ	Junction Capacitance
I _F	Forward Current
V _F	Forward Voltage @ I _F



Electrical characteristics per line@25℃(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				12	V
Breakdown Voltage	V _{BR}	I _t =1mA		14.5		V
Reverse Leakage Current	I _R	V _{RWM} =12V			1	μA
Clamping Voltage	Vc	I _{PP} =8A t _P = 8/20µs		20		V
Junction Capacitance	C _j	V _R =0V f = 1MHz		46		pF

Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µS)	P _{pp}	180	W
Lead Soldering Temperature	T∟	260 (10 sec)	$^{\circ}$
Operating Temperature	TJ	-55 to 125	$^{\circ}$
Storage Temperature	T _{STG}	-55 to 150	$^{\circ}$

Typical Characteristics

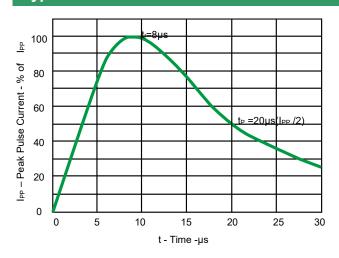


Fig 1.Pulse Waveform

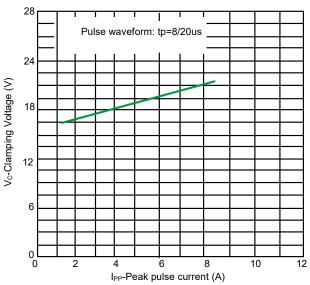


Fig 3. Clamping voltage vs. Peak pulse current

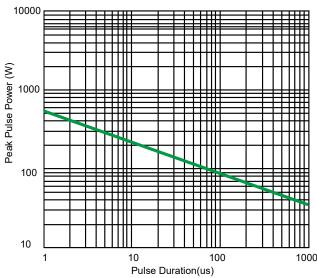


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

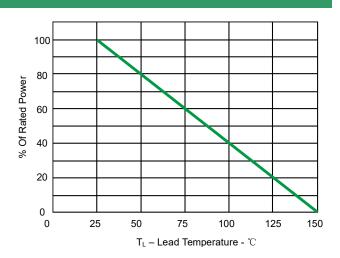


Fig 2.Power Derating Curve

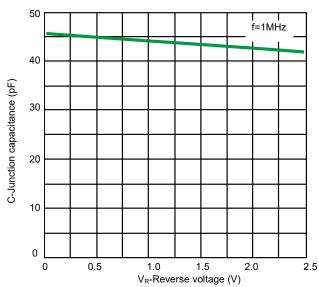
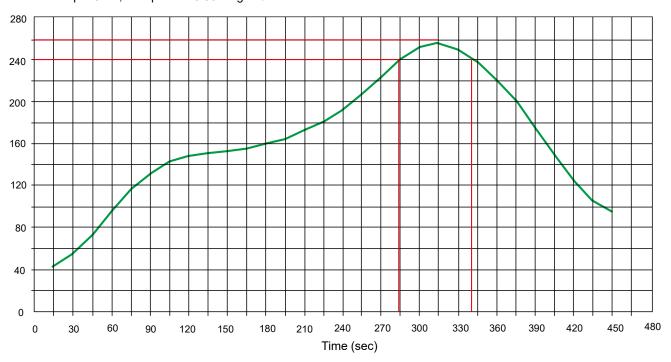


Fig 4. Capacitance vs. Reveres voltage

Solder Reflow Recommendation

Peak Temp=257℃, Ramp Rate=0.802deg. ℃/sec

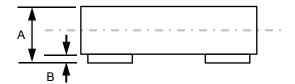


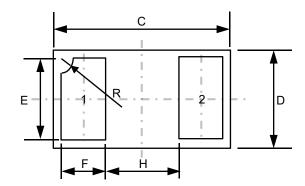
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

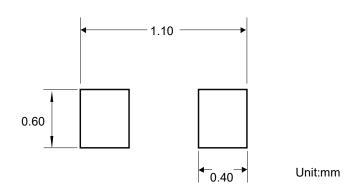
- Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- Keep the length of via holes in mind! The longer the more inductance they will have.

Product dimension (DFN1006-2L)





Dim	Inches		Millimeters		
Dim	MIN	MAX	MIN	MAX	
А	0.013	0.020	0.34	0.50	
В	0.000	0.002	0.00	0.05	
С	0.037	0.043	0.95	1.080	
D	0.022	0.027	0.55	0.680	
E	0.016	0.024	0.40	0.60	
F	0.008	0.012	0.20	0.30	
Н	0.015Typ.		0.40Тур.		
R	0.001	0.005	0.05	0.15	

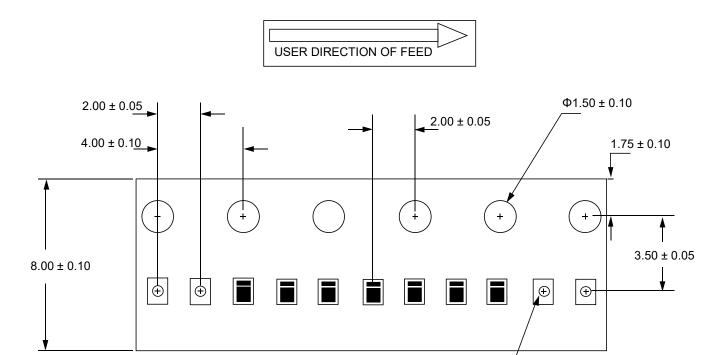


Suggested PCB Layout

Ordering information

Device	Package	Reel	Shipping
PESDHC2FD12VU	DFN1006-2L (Pb-Free)	7"	10000 / Tape & Reel

Load with information



Unit: mm

_Ф0.50 ± 0.05

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